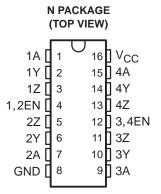
SLLS039B - OCTOBER 1980 - REVISED MAY 1995

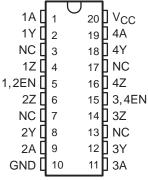
- Meets or Exceeds the Requirements of ANSI Standards EIA/TIA-422-B and RS-485 and ITU Recommendation V.11.
- Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments
- 3-State Outputs
- Common-Mode Output Voltage Range of –7 V to 12 V
- Active-High Enable
- Thermal Shutdown Protection
- Positive- and Negative-Current Limiting
- Operates From Single 5-V Supply
- Low Power Requirements
- Functionally Interchangeable With MC3487

## description

The SN75174 is a monolithic quadruple differential line driver with 3-state outputs. It is designed to meet the requirements of ANSI Standards EIA/TIA-422-B and RS-485 and ITU Recommendation V.11. The device is optimized for balanced multipoint bus transmission at rates up to 4 megabaud. Each driver features wide positive and negative common-mode output voltage ranges making it suitable for party-line applications in noisy environments.







NC - No internal connection

The SN75174 provides positive- and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. Shutdown occurs at a junction temperature of approximately 150°C. This device offers optimum performance when used with the SN75173 or SN75175 quadruple differential line receivers.

The SN75174 is characterized for operation from 0°C to 70°C.

# FUNCTION TABLE (each driver)

INPUT	ENABLE	OUT	PUTS
INFUI	ENABLE	Υ	Z
Н	Н	Н	L
L	Н	L	Н
Х	L	Z	Z

H = TTL high level, X = irrelevant,

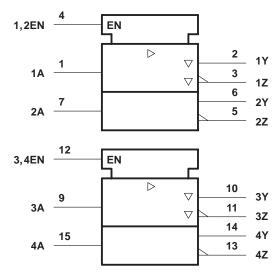
L = TTL low level, Z = high impedance (off)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

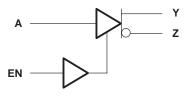


## logic symbol†

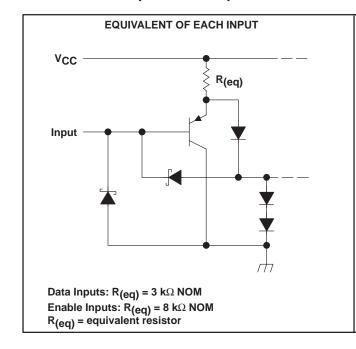


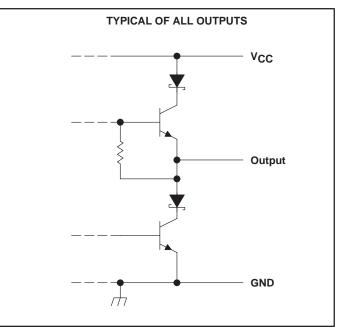
# † This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

# logic diagram, each driver (positive logic)



## schematics of inputs and outputs





SLLS039B - OCTOBER 1980 - REVISED MAY 1995

# absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1)	
Output voltage range, VO	
Input voltage, V <sub>I</sub>	5.5 \
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	0°C to 70°C
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTE 1: All voltage values are with respect to the network ground terminal.

#### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{\scriptsize A}} \le 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^{\circ}C$	T <sub>A</sub> = 70°C POWER RATING
DW	1125 mW	9.0 mW/°C	720 mW
N	1150 mW	9.2 mW/°C	736 mW

## recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>	4.75	5	5.25	V
High-level input voltage, VIH	2			V
Low-level input voltage, V <sub>IL</sub>			0.8	V
Common-mode output voltage, V <sub>OC</sub>		-	7 to 12	V
High-level output current, IOH			-60	mA
Low-level output current, IOL			60	mA
Operating free-air temperature, T <sub>A</sub>	0		70	°C



<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

SLLS039B - OCTOBER 1980 - REVISED MAY 1995

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
VIK	Input clamp voltage	$I_{I} = -18 \text{ mA}$				-1.5	V
Vон	High-level output voltage	$V_{IH} = 2 V$ , $I_{OH} = -33 \text{ mA}$	V <sub>IL</sub> = 0.8 V,		3.7		V
VOL	Low-level output voltage	V <sub>IH</sub> = 2 V, I <sub>OL</sub> = 33 mA	V <sub>IL</sub> = 0.8 V,		1.1		٧
٧o	Output voltage	I <sub>O</sub> = 0		0		6	V
V <sub>OD1</sub>	Differential output voltage	I <sub>O</sub> = 0		1.5	6	6	V
IV <sub>OD2</sub> I	Differential output voltage	R <sub>L</sub> = 100 Ω,	See Figure 1	1/2 V <sub>OD1</sub> or 2 <sup>‡</sup>			V
		$R_L = 54 \Omega$ ,	See Figure 1	1.5	2.5	5	V
V <sub>OD3</sub>	Differential output voltage	See Note 2		1.5		5	V
Δ V <sub>OD</sub>	Change in magnitude of differential output voltage§					±0.2	V
Voc	Common-mode output voltage¶	$R_L = 54 \Omega \text{ or } 10$	$\Omega$ 0 Ω, See Figure 1			+3 -1	٧
∆IVocI	Change in magnitude of common-mode output voltage§	]				±0.2	V
I <sub>O</sub>	Output current with power off	V <sub>CC</sub> = 0,	$V_0 = -7 \text{ V to } 12 \text{ V}$			±100	μΑ
IOZ	High-impedance-state output current	$V_0 = -7 \text{ V to } 1$	2 V			±100	μΑ
lН	High-level input current	V <sub>I</sub> = 2.7 V				20	μА
Iμ	Low-level input current	V <sub>I</sub> = 0.5 V				-360	μΑ
		V <sub>O</sub> = -7 V				-180	
los	Short-circuit output current	VO = VCC			180	mA	
		V <sub>O</sub> = 12 V				500	
loo	Supply current (all drivers)	No load	Outputs enabled		38	60	mA
Icc	Supply current (all univers)	INO IOAU	Outputs disabled		18	40	IIIA

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$  and  $T_A = 25^{\circ}\text{C}$ .

NOTE 2: See EIA Standard RS-485.

# switching characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST (	MIN	TYP	MAX	UNIT	
td(OD)	Differential-output delay time	$R_1 = 54 \Omega$	See Figure 2		45	65	ns
t <sub>t</sub> (OD)	Differential-output transition time	KL = 54 52,	See Figure 2		80	120	ns
<sup>t</sup> PZH	Output enable time to high level	$R_L = 110 \Omega$ ,	See Figure 3		80	120	ns
tPZL	Output enable time to low level	$R_L = 110 \Omega$ ,	See Figure 4		55	80	ns
<sup>t</sup> PHZ	Output disable time from high level	$R_L = 110 \Omega$ ,	See Figure 3		75	115	ns
tPLZ	Output disable time from low level	$R_L = 110 \Omega$ ,	See Figure 3		18	30	ns



 $<sup>\</sup>ddagger$  The minimum VOD2 with a 100- $\Omega$  load is either 1/2 VOD1 or 2 V, whichever is greater.

<sup>§ ∆|</sup>V<sub>OD</sub>| and ∆|V<sub>OC</sub>| are the changes in magnitude of V<sub>OD</sub> and V<sub>OC</sub>, respectively, that occur when the input is changed from a high level to a low level.

<sup>¶</sup> In ANSI Standard EIA/TIA-422-B, V<sub>OC</sub>, which is the average of the two output voltages with respect to ground, is called output offset voltage, V<sub>OS</sub>.

#### **SYMBOL EQUIVALENTS**

DATA SHEET PARAMETER	EIA/TIA-422-B	RS-485
Vo	$V_{oa}$ , $V_{ob}$	V <sub>oa</sub> , V <sub>ob</sub>
IV <sub>OD1</sub> I	Vo	V <sub>o</sub>
V <sub>OD2</sub>	$V_t (R_L = 100 \Omega)$	$V_t (R_L = 54 \Omega)$
lV <sub>OD3</sub> l		V <sub>t</sub> (Test Termination) Measurement 2)
Δ V <sub>OD</sub>	$  V_t  -  \overline{V}_t  $	$   V_t  -  \overline{V}_t   $
Voc	V <sub>os</sub>	V <sub>os</sub>
Δ V <sub>OC</sub>	$ V_{OS} - \overline{V}_{OS} $	$ V_{OS} - \overline{V}_{OS} $
los	I <sub>sa</sub>  , I <sub>sb</sub>	
lo	$ I_{xa} , I_{xb} $	lia, <sup>l</sup> ib

## PARAMETER MEASUREMENT INFORMATION

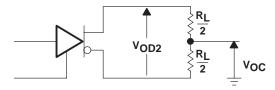
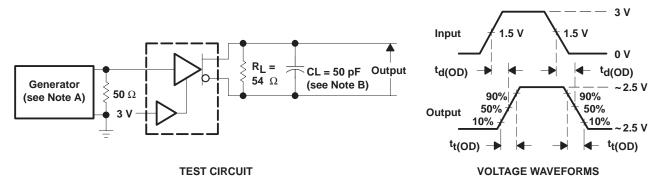


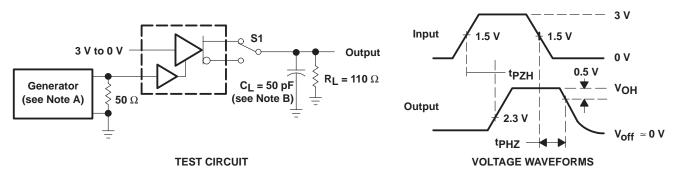
Figure 1. Differential and Common-Mode Output Voltages



- NOTES: A. The input pulse is supplied by a generator having the following characteristics:  $t_{\Gamma} \le 5$  ns,  $t_{f} \le 5$  ns, PRR  $\le 1$  MHz, duty cycle = 50%,  $Z_{O} = 50 \Omega$ .
  - B. C<sub>L</sub> includes probe and stray capacitance.

Figure 2. Differential-Output Test Circuit and Voltage Waveforms

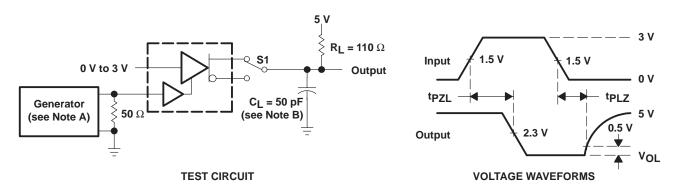
#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, duty cycle = 50%,  $t_f \leq$  5 ns,  $Z_O = 50 \ \Omega$ .

B. C<sub>L</sub> includes probe and stray capacitance.

Figure 3. Test Circuit and Voltage Waveforms



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, duty cycle = 50%,  $t_f \leq$  5 ns,  $Z_O = 50 \ \Omega$ .

B. C<sub>L</sub> includes probe and stray capacitance.

Figure 4. Test Circuit and Voltage Waveforms



#### **TYPICAL CHARACTERISTICS**

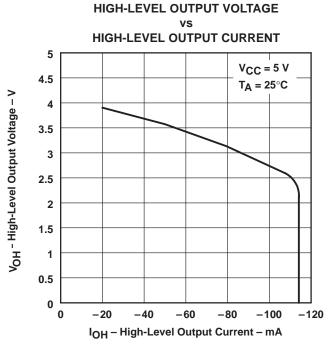


Figure 5

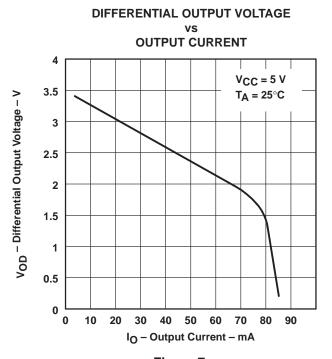


Figure 7

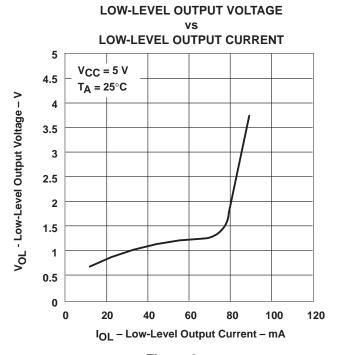


Figure 6

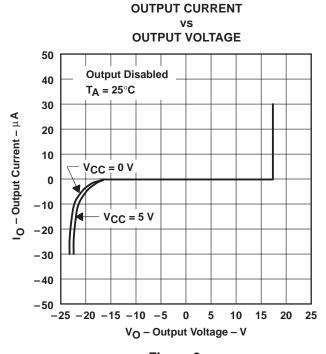
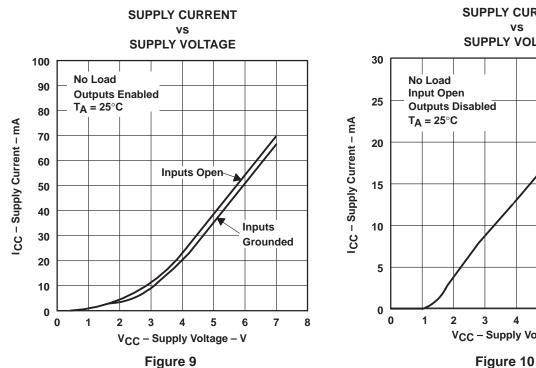
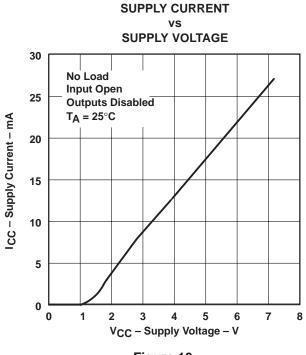


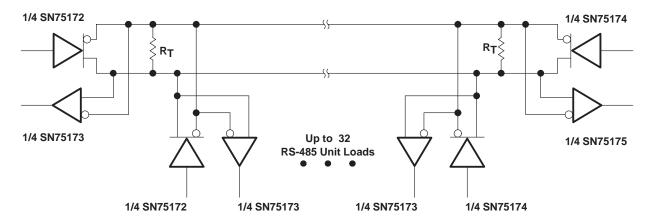
Figure 8

#### TYPICAL CHARACTERISTICS





## **APPLICATION INFORMATION**



NOTE: The line length should be terminated at both ends in its characteristic impedance (R<sub>T</sub> = Z<sub>O</sub>). Stub lengths off the main line should be kept as short as possible.

Figure 11. Typical Application Circuit



www.ti.com 14-Aug-2021

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN75174DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75174	Samples
SN75174DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75174	Samples
SN75174DWRE4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75174	Samples
SN75174DWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75174	Samples
SN75174N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75174N	Samples
SN75174NE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	SN75174N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



## PACKAGE OPTION ADDENDUM

www.ti.com 14-Aug-2021

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# PACKAGE MATERIALS INFORMATION

www.ti.com 16-Oct-2019

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75174DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

www.ti.com 16-Oct-2019



#### \*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	SN75174DWR	SOIC	DW	20	2000	367.0	367.0	45.0	

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (https://www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2021, Texas Instruments Incorporated